LX8213



PRODUCTION DATASHEET

300mA Low Noise CMOS LDO Regulator

DESCRIPTION

The LX8213 LDO regulator is part of Microsemi's family of positive voltage regulator ICs using CMOS technology. The device provides a compact and cost effective solution featuring low power consumption over a wide supply voltage range, high output voltage accuracy, low dropout, excellent line and load regulation, fast transient response, and low noise.

The LX8213 operates over a wide input voltage range of 2.5V to 6V, and consumes only 60uA typical quiescent current at no load and a low 0.1uA shutdown current. Output voltage options include fixed 1.0V, 1.2V, 3.3V, or an adjustable output voltage which may be set from 800mV to 5.5V. The LDO delivers up to 300mA of output current, with a foldback current limit of approximately 400mA. At 300mA load, dropout voltage measures only 170mV for a 3.3V output.

Tight load and line regulation is achieved over the full output current and supply range. The high bandwidth control loop provides fast transient response to reduce output voltage deviation using low cost external ceramic capacitors in the 1uF range.

The LX8213 also exhibits low output noise with only $60 \text{uV}_{\text{RMS}}$ over a 100 kHzbandwidth. Power supply rejection exceeds 65dB at 100Hz.

Other features of LX8213 include an active low shutdown input with a $3M\Omega$ internal pull-down for low cost power sequencing, internal soft-start circuitry to prevent inrush current, short circuit current limit, and thermal overload protection.

The LX8213 operates over -40°C to +85°C ambient temperature range and is available in a tiny 5 pin SOT-23 ROHS compliant package.

KEY FEATURES

- 2.5V to 6V Wide Input Voltage Range
- Fixed Output: 1.0V, 1.2V, 3.3V, or 0.8V to 5.5V Adjustable Output Voltage Range
- Low Quiescent Current of Typical 60uA
- Low Dropout Voltage of Typical 170mV at 3.3V 300mA
- Stable with Low ESR 1uF Input/Output Bypass Ceramic Capacitors
- Ultra Low Shutdown Current of Typical 0.1uA
- Low Output Noise of Typical 60uV_{RMS} at VOUT=0.8V
- Fast Transient Response
- Shutdown Control Input
- Foldback Current Limit
- 50mA Short Circuit Limit
- Over Temperature Protection
- Standard Package SOT-23
- RoHS Compliant

APPLICATIONS

- Battery Operated Systems
- Set-Top Box
- LCD TV's
- Routers
- Video Cards
- Hand Held Instruments

	PACKAG	THERMAL DATA				
	SE	Plastic SOT-23	5-pin	$\theta_{\rm JA} = 250 ^{\circ}{\rm C/W}$		
T _A (°C)	RoHS Compliant / Pb-free			THERMAL RESISTANCE- JUNCTION TO AMBIENT		
-40 to +85	LX8213-10ISE (1 LX8213-12ISE (1	djustable) Marking .0V Fixed Output) .2V Fixed Output) .3V Fixed Output)	Marking "FAJ" Marking "FAK"	Junction Temperature Calculation: $T_J = T_A + (P_D \ x \ \theta_{JA}).$ The θ_{JA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no		
Note: Availat	ele in Tape & Reel. Append the	ambient airflow.				

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AABSOLUTE MAXIMUM RATINGS	PACKAGE PIN OUT			
VIN	SHDN 1 5 FB/NC			
Output Current	GND 2 VIN 3 4 VOUT			
Note: Exceeding these ratings could cause damage to the device. All voltages are with respect to ground. Currents are positive into and negative out of the specified terminal.	SE PACKAGE (Top View) RoHS / Pb-free 100% Matte Tin Pin Finish			

Name	Pin#	Description
SHDN	1	Active Low Shutdown Input. Connect to VIN or a logic level high to enable the device. An internal 3MΩ pull-down resistor disables the device when the SHDN pin is floating.
GND	2	Ground. Connect to the local analog ground or to the circuit board ground plane to maximize thermal dissipation. Bypass the input and output capacitors to this plane.
VIN	3	Regulator Input. Operating voltage range is from 2.5V to 6V. Bypass VIN to GND with a 1uF capacitor.
VOUT	4	Regulator Output. Bypass to GND with a 1uF capacitor.
FB (Adjustable Output Version)	5	Feedback Input. For the adjustable output version (LX8213-00), the device output voltage can be set from 0.8V to 5.5V by connecting FB to the center of a resistive voltage divider from VOUT to GND. Note that FB regulates to 0.8V.
N.C. (Fixed Output Version)	5	No Connect. For fixed output versions, pin 5 is a no connect.



DATASHEET LX8213

300mA Low Noise CMOS LDO Regulator

ELECTRICAL CHARACTERISTICS

LX8213-00ISE (Adjustable Output). Unless otherwise specified, the following specifications apply over the operating temperature of -40°C \leq T_A \leq 85°C with the following test conditions: VIN=(VOUT+1), VIN_{MIN}=2.5V, \overline{SHDN} = HIGH, C_{IN}=1 μ F, C_{OUT}=1 μ F

Parameter	Symbol Test Conditions		LX8213-00			Units
			Min	Тур	Max	Omits
LX8213-00ISE (ADJUSTABLE OUT	PUT)					
Reference Voltage	V_{REF}	2.5V ≤ VIN ≤ 6V	0.784	0.8	0.816	V
Input Voltage	VIN		2.5		6	V
Maximum Output Current	I _{OUT} (MAX)		300	400		mA
Load Regulation	ΔVOUT / VOUT	1mA ≤ I _{OUT} ≤ 300mA			0.4	%
Line Regulation	ΔVOUT / VOUT	$(VOUT+0.5V) \le VIN \le 6V, VIN_{MIN}=2.5V,$ $I_{OUT}=30mA$			0.2	%
Dropout Voltage	V_{DROP}	V _{OUT} =3.3V, I _{OUT} =300mA, ΔVOUT=-1%		170	300	mV
Quiescent Current	ΙQ	I _{OUT} =0mA		60	90	μA
Shutdown Current	I _{SHDN}	SHDN = LOW		0.1	1.0	μA
Power Supply Rejection Ratio	PSRR Ripple 1Vpp, VIN=3V			68 68		dB
. errer euppry regeenem rane		VIN=3V f=10kHz		54		
Output Voltage Temperature Coefficient	(ΔVOUT/VOUT) /ΔT	I_{OUT} =30mA, -40°C \leq T_A \leq 85°C		±100		ppm/°C
Short Current Limit	I _{SHORT}	VOUT=0V		50		mA
Soft Start Time	t _{UP}			50		uS
RMS Output Noise	V _{NOISE}	T _A =25°C, 10Hz ≤ f ≤ 100kHz, VOUT=0.8V		60		uV _{RMS}
Shutdown "High" Logic Threshold (Device Enabled)			1.5		6	٧
Shutdown "Low" Logic Threshold (Device Disabled)			0		0.4	٧
VOUT Discharge Internal MOSFET R _{DS(ON)}		SHDN = LOW		60		Ω
Shutdown Internal Pull Down Resistance				3		ΜΩ
Thermal Shutdown				165		°C
Thermal Shutdown Hysteresis				30		°C



LX8213

300mA Low Noise CMOS LDO Regulator

ELECTRICAL CHARACTERISTICS

LX8213-10ISE/-12ISE/-33ISE (Fixed Output). Unless otherwise specified, the following specifications apply over the operating temperature of - $40^{\circ}\text{C} \leq T_{\text{A}} \leq 85^{\circ}\text{C}$ with the following test conditions: VIN=2.5V for VOUT=1.0V/1.2V, VIN=(VOUT+1V) for VOUT=3.3V, $\overline{\text{SHDN}}$ = HIGH, C_{IN} =1 μ F, C_{OUT} =1 μ F

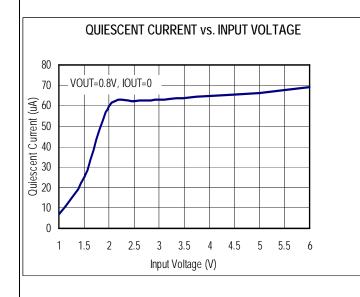
Parameter	Symbol Test Conditions		LX8213-10/12/33			Units	
			Min	Тур	Max	Ullits	
LX8213-10ISE (1.0V), LX8213-12ISI	E (1.2V), LX8213-33	BISE (3.3V) (FIXED OUTPUT)					
Output Voltage	VOUT	1mA ≤ I _{OUT} ≤ 300mA		98%* VOUT		102%* VOUT	V
Input Voltage	VIN			2.5		6	V
Maximum Output Current	I _{OUT} (MAX)			300	400		mA
Load Regulation	ΔVOUT / VOUT	1mA ≤ I _{OUT} ≤ 300mA	1mA ≤ I _{OUT} ≤ 300mA			0.4	%
Line Regulation	ΔVOUT / VOUT	$2.5V \le VIN \le 6V$ for VOUT=1.0V/1.2V, (VOUT+0.5V) $\le VIN \le 6V$ for VOUT=3.3V, I_{OUT} =30mA				0.2	%
Dropout Voltage	V_{DROP}	VOUT=3.3V, I _{OUT} =300mA, ΔVOUT=-1%			170	300	mV
Quiescent Current	ΙQ	I _{OUT} =0mA			60	90	uA
Shutdown Current	I _{SHDN}	SHDN = LOW			0.1	1.0	uA
	PSRR	Ripple 1Vpp,		68			
Power Supply Rejection Ratio				68 54		dB	
Output Voltage Temperature Coefficient	(ΔVOUT/VOUT) /ΔT	VIN=4.3V for VOUT=3.3V f=10kHz I_{OUT} =30mA, -40°C \leq T _A \leq 85°C			±100		ppm/°C
Short Current Limit	I _{SHORT}	VOUT=0V			50		mA
Soft Start Time	t _{UP}				50		uS
Shutdown "High" Logic Threshold (Device Enabled)				1.5		6	V
Shutdown "Low" Logic Threshold (Device Disabled)				0		0.4	V
VOUT Discharge Internal MOSFET R _{DS(ON)}		SHDN = LOW			60		Ω
Shutdown Internal Pull Down Resistance					3		МΩ
Thermal Shutdown					165		°C
Thermal Shutdown Hysteresis					30		°C

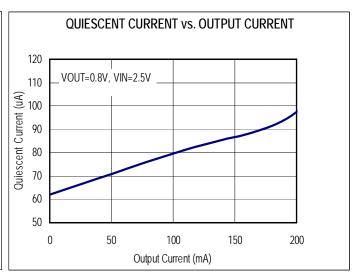


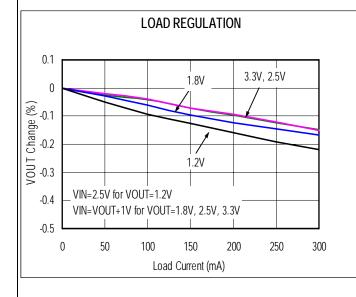
LX8213

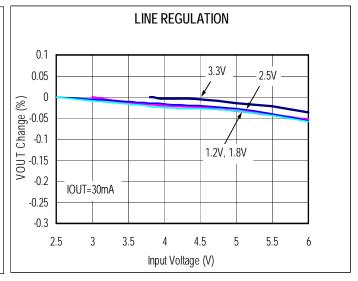
300mA Low Noise CMOS LDO Regulator

TYPICAL CHARACTERISTICS @ 25°C



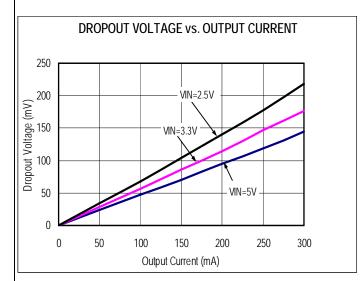


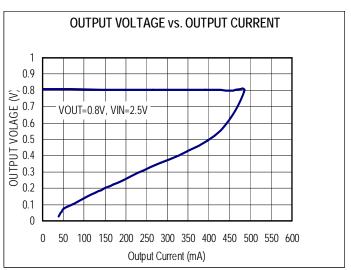




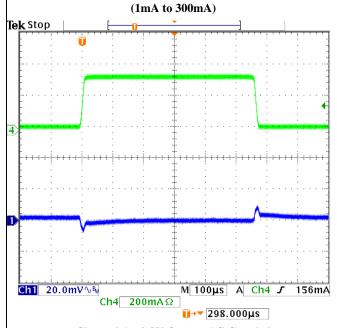


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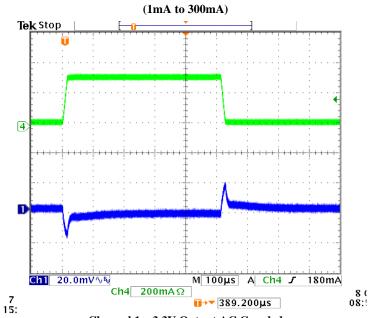


LOAD TRANSIENT RESPONSE



 $\label{eq:Channel 1-0.8V Output AC Coupled} Channel 4-Output Current 1mA to 300mA, \\ Slew Rate = 0.02A/uS$

LOAD TRANSIENT RESPONSE



Channel 1 – 3.3V Output AC Coupled

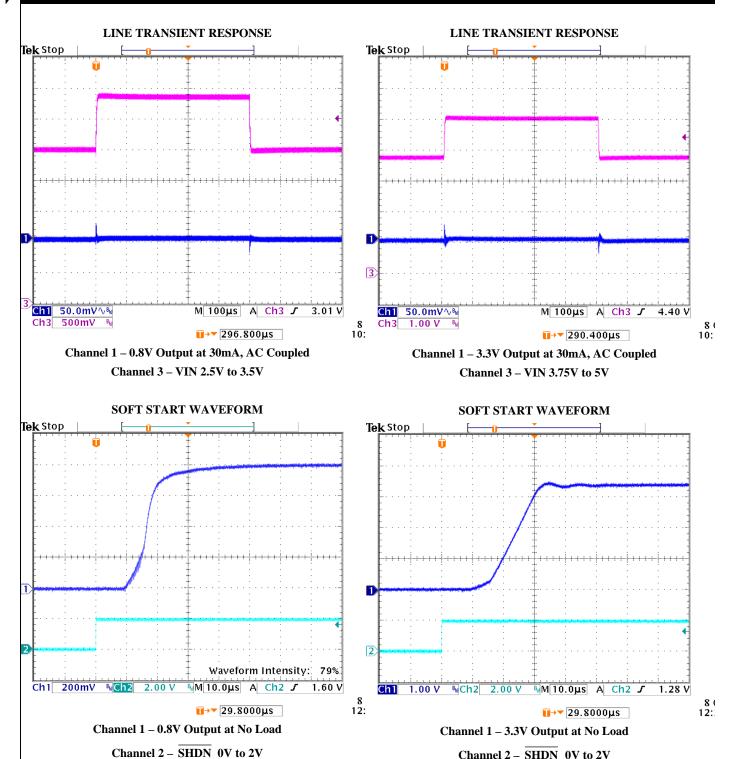
Channel 4 – Output Current 1mA to 300mA,

Slew Rate = 0.02A/uS



300mA Low Noise CMOS LDO Regulator

TYPICAL CHARACTERISTICS @ 25°C

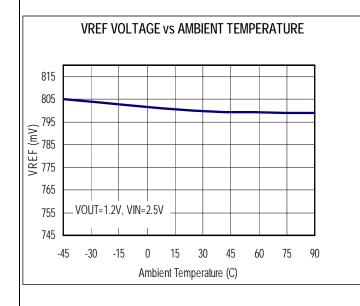


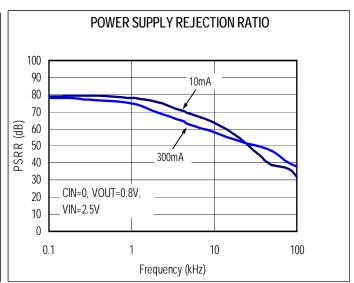


LX8213

300mA Low Noise CMOS LDO Regulator

TYPICAL CHARACTERISTICS @ 25°C







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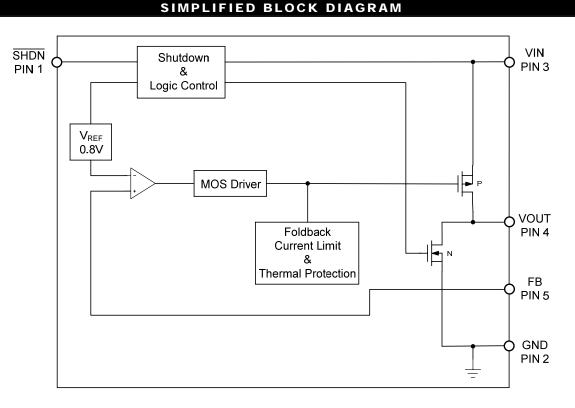
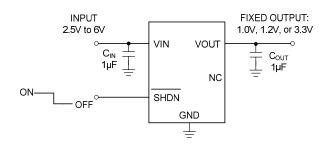


Figure 1 - LX8213-00 (Adjustable Output) Simplified Block Diagram

APPLICATION SCHEMATIC



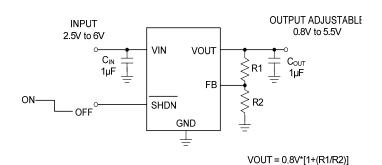


Figure 2 - LX8213-10/12/33 Fixed Output Version **Application Schematic**

Figure 3 - LX8213-00 Adjustable Output Application Schematic

300mA Low Noise CMOS LDO Regulator

APPLICATION INFORMATION

Description

The LX8213 is a family of CMOS based LDO (Low Drop-Out) The LX8213 uses a foldback current limit. When the load current regulators in a small 5 pin SOT-23 package that provides a compact and cost effective solution. The LX8213 is offered with fixed output voltages of 1.0V, 1.2V, or 3.3V, in addition to an adjustable version with an output voltage range of 0.8V to 5.5V. The LX8213 features low power consumption over a wide supply voltage range, high output voltage accuracy, low dropout, excellent line and load regulation, fast transient response, and low noise. Please refer to the Electrical Characteristics Table for the specifications.

Input Capacitor

To improve load transient response and noise rejection, an input bypass capacitor is recommended, but it is not required for stability. There are no requirements for the ESR (Equivalent Series Resistor) on the input capacitor, but tolerance and temperature coefficient must be considered when selecting the capacitor to ensure the capacitor will be around 1µF over the entire operating temperature range. Capacitors with X5R or X7R characteristics are recommended.

Output Capacitor

For stability of the regulator, use a minimum 1uF capacitor to bypass from VOUT to GND. Note that the LX8213 is stable using low ESR ceramic capacitors. Capacitors with X5R or X7R characteristics generally perform well and are recommended.

Adjustable Output Voltage

The LX8213-00 output voltage can be set within the range of 0.8V to 5.5V by connecting the FB pin to an external resistor divider (See Figure 3). The output voltage can be calculated using:

$$V_{OUT} = 0.8 \left[1 + \frac{R1}{R2} \right]$$

R2 is chosen to minimize the power dissipated by the resistor divider network while providing enough FB input bias current. A value of $8.06k\Omega$ is recommended.

Shutdown (SHDN)

Rev. 1.0. 2009-03-18

The LX8213 includes an active low shutdown input (SHDN).

When the SHDN pin is left floating, an internal pull down resistor to GND of $3M\Omega$ will automatically disable the device. Upon shutdown, an internal MOSFET connected from VOUT to GND will be turned ON to discharge the output capacitor.

To enable the regulator, set SHDN to logic high. If shutdown capability is not required, connect SHDN pin to VIN. For specification on minimum and maximum logic high levels, please refer to the Electrical Characteristics Table.

Foldback Current Limit

exceeds approximately 400mA, the output voltage is reduced along with the output current, minimizing power dissipated and protecting the device from excessive heating.

Short Circuit Current Protection

Under conditions where the output of the LX8213 is shorted to ground, internal circuitry will limit the device to source only about 50mA.

Temperature Protection

The thermal protection shuts down the LX8213 when the junction temperature exceeds approximately 165°C, with a hysteresis of about 30°C.

Thermal Consideration

Thermal shutdown protects the integrated circuit from thermal overload caused from a rise in junction temperature during power dissipation. This means the protection is intended for fault protection only and not as a means of current or power limiting during normal application usage. Proper thermal evaluation should be done to ensure that the junction temperature dose not exceed it's maximum rating. Operating at the maximum T_J of 150°C can impact reliability. Due to variation in individual device electrical characteristics and thermal resistance, the built in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.

Power dissipation for regulator can be calculated using the following equation:

$P_D = (V_{IN(MAX)} - V_{OUT(MIN)}) * I_{OUT(MAX)}$

(Note: power dissipation resulting from quiescent current is negligible)

For the SOT23 package, thermal resistance, θ_{JA} is 250°C/W when mounted on a FR4 copper clad PCB. Junction temperature of the integrated circuit can be calculated using:

$$T_J = T_A + T_{RISE}$$
, substituting: $T_A + (P_D * \theta_{JA})$.

An example: Given conditions: $T_A = 25$ °C, $V_{IN} = 2.5$ V, $V_{OUT} = 1.0$ V, I_{OUT} = 200mA.

Calculated values:

Total Power dissipation $P_{D(total)} = (2.5-1.0) \text{ V} * 0.2\text{A} = 0.3\text{W}$ $T_J = 25^{\circ}C + (0.3W *250^{\circ}C/W) = 100^{\circ}C$ Junction Temperature

LX8213



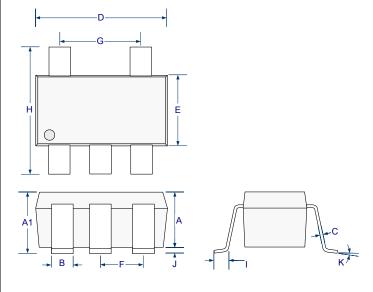
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300mA Low Noise CMOS LDO Regulator

PACKAGE DIMENSION

SE

5 Pin Plastic SOT-23



	MILLIM	ETERS	INCHES		
Dim	MIN	MAX	MIN	MAX	
Α	0.90	1.30	0.035	0.051	
A1	0.90	1.45	0.035	0.057	
В	0.25	0.50	0.010	0.020	
С	0.09	0.20	0.004	0.008	
D	2.80	3.10	0.110	0.122	
E	1.50	1.75	0.059	0.069	
F	0.95	BSC	0.038 BSC		
G	1.90 BSC		0.075	BSC	
Н	2.60	3.00	0.102	0.118	
I	0.35	0.55	0.014	0.022	
J	0.00	0.15	0.000	0.006	
K	10° I	MAX	10° I	MAX	

Note:

 Dimensions do not include mold flash or protrusions; these shall not exceed 0.155mm(.006") on any side. Lead dimension shall not include solder coverage.

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